NSN 5961-00-104-0114

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-104-0114 **Inclosure Material:** Glass **Overall Length:** Between 0.245 inches and 0.280 inches **Terminal Length:** 0.3475 inches **Overall Height:** Between 0.035 inches and 0.059 inches **Overall Width:** 0.155 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 30.0 collector to base voltage/static/emitter open all transistor and 30.0 collector to emitter voltage/static/base open all transistor and 15.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 100.00 milliamperes collector current, dc all transistor **Power Rating Per Characteristic:** 1.0 watts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0